

2SK2569 Silicon N Channel MOS FET

REJ03G1018-0300 Rev.3.00 Dec 27, 2006

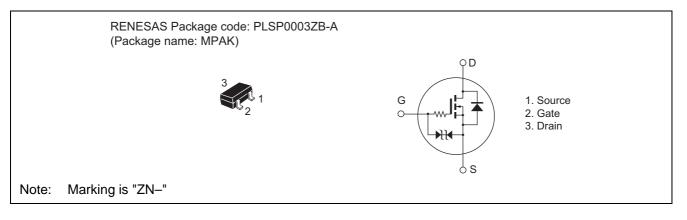
Application

High speed power switching

Features

- Low on-resistance.
- $R_{DS(on)} = 2.6 \ \Omega \ max.$ (at $V_{GS} = 4 \ V, I_D = 100 \ mA$)
- 2.5 V gate drive device.
- Small package (MPAK).

Outline





Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	50	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	0.2	А
Drain peak current	I _{D(pulse)} * ¹	0.4	А
Channel dissipation	Pch* ²	150	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note: 1. PW \leq 10 μ s, duty cycle \leq 1 %

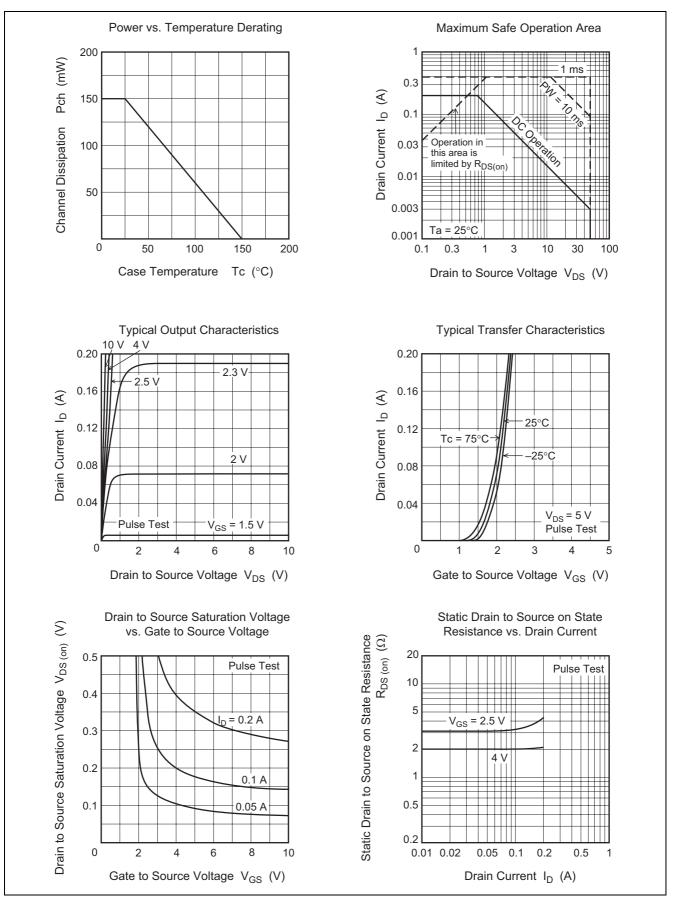
Electrical Characteristics

						(Ta = 25°C)
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	50	—	—	V	$I_D = 100 \ \mu A, \ V_{GS} = 0$
Gate to source breakdown voltage	V _{(BR)GSS}	±20	—	—	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	—	1.0	μA	$V_{DS} = 40 V, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	—	±2.0	μA	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	0.5	—	1.5	V	$I_D = 10 \ \mu A, \ V_{DS} = 5 \ V$
Static drain to source on state resistance	R _{DS(on)1}	—	2.0	2.6	Ω	$I_D = 100 \text{ mA}, V_{GS} = 4 \text{ V}^{*2}$
Static drain to source on state resistance	R _{DS(on)2}	_	3.1	5.0	Ω	$I_D = 40$ mA, $V_{GS} = 2.5$ V* ²
Forward transfer admittance	y _{fs}	0.13	0.23	—	S	$I_D = 100 \text{ mA}, V_{DS} = 10 \text{ V}$
Input capacitance	Ciss	_	14.0	_	pF	$V_{DS} = 10 V, V_{GS} = 0,$
Output capacitance	Coss		17.2	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss		1.73		pF	
Turn-on delay time	t _{d(on)}	_	40	—	ns	$\label{eq:GS} \begin{array}{l} V_{GS} = 10 \text{ V}, \text{ I}_{D} = 100 \text{ mA}, \\ R_{L} = 300 \ \Omega \end{array}$
Rise time	tr	_	86	—	ns	
Turn-off delay time	t _{d(off)}	_	1120	—	ns	
Fall time	t _f		430	—	ns]

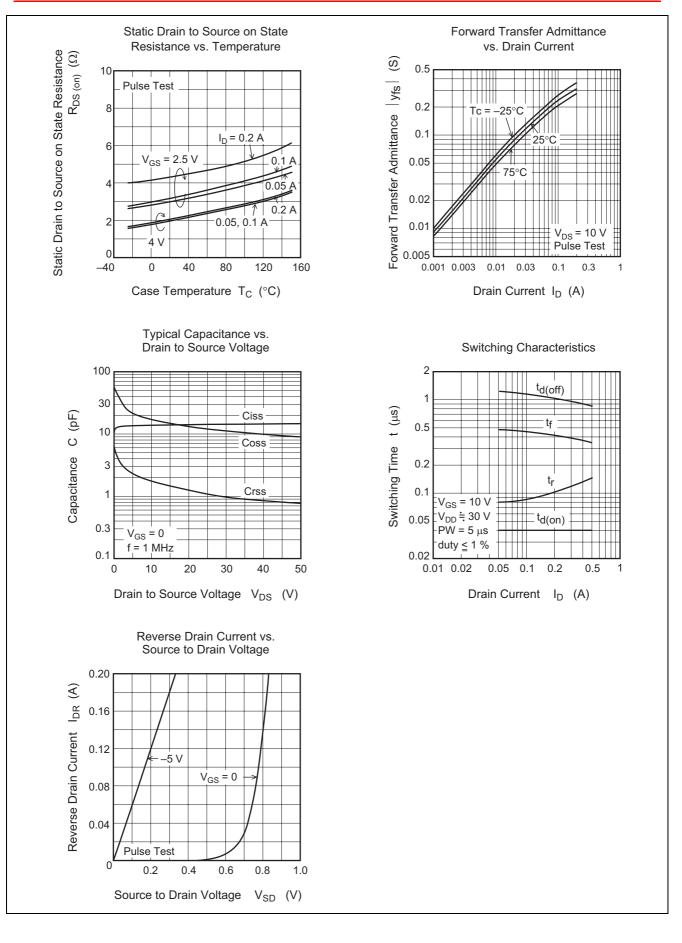
Note: 2. Pulse test



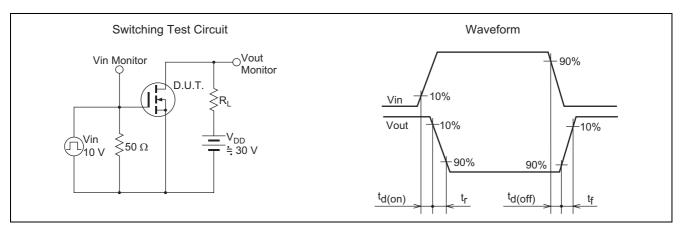
Main Characteristics





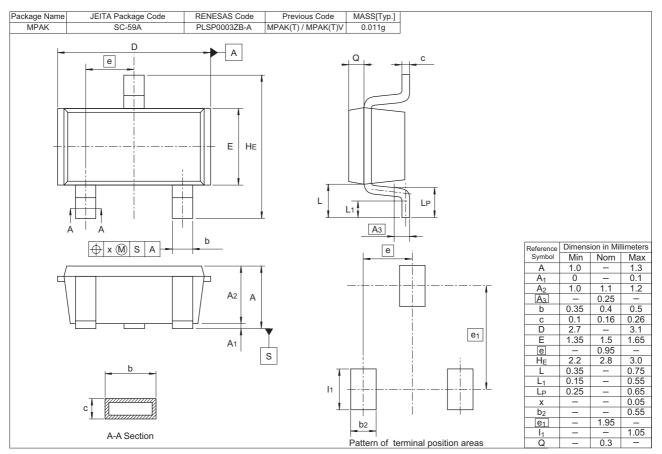








Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SK2569ZN-TL-E	3000 pcs	Taping
2SK2569ZN-TR-E	3000 pcs	Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



RenesasTechnology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

- Benesas lechnology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
 Pines
 This document is provided for reference purposes only so that Renesas customers may select the appropriate Renesas products for their use. Renesas neither makes warranties or representations with respect to the accuracy or completeness of the information in this document.
 But not infinited to, product data. diagrams, charts, programs, algorithms, and application scule as the development of weapons of mass and regulations, and proceedures required by such laws and regulation.
 All information in the burgose of any other military use. When exporting the products or the technology described herein, you should follow the applicable export control laws and regulations, and proceedures required by such laws and regulations.
 All information included in this document, buch as product data, diagrams, charts, programs, algorithms, and application oracit useraphes, is current as of the date this document, buch as product data, diagrams, charts, programs, algorithms, and application incluit examples, is current as of the date their document, when exporting the products or the technology described herein, you should follow the applicable export control laws and regulations.
 Renesas has used reasonable care in compiling the information in this document, but Renesas assumes no liability whatsoever for any damages incurred as a fast of the date different information in the date their document.
 When using or otherwise regulations in the information in this document, but Renesas assumes no liability whatsoever for any damages incurred as a different information in this document.
 When using or otherwise regulations in the information in the date their document.
 When using or otherwise regulations in the failure of a motification and traffic to the sease as products are not designed publication control. Accross are no



RENESAS SALES OFFICES

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K. Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd. Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7898

Renesas Technology Hong Kong Ltd. 7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology Singapore Pte. Ltd.

1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

http://www.renesas.com